

GaAs Broadband Cartesian QPSK Optical Modulator

Product code: SCM01120



Features

- Incorporates two Mach-Zehnder modulators in parallel
- Enables complete control of the optical intensity and phase
- Flat frequency response over 20 GHz
- Low drive voltage $V_{\pi} = 3.0 \text{ V}$

Applications

- Broadband digital communications (40 Gbit/s)
- QPSK and DQPSK transmission
- Suitable for 8-PSK and QAM transmission

The SCM01120 is a low loss, high integrity Cartesian optical modulator (so called because it can control the optical intensity and phase to reach any point in the complex plane) based on gallium arsenide designed for general-purpose applications over the frequency range DC-20 GHz. The die is fabricated using well proven and exercised high volume gallium arsenide processes used in the telecommunications industry that offers market leading performance optimized for optical applications.

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Operation Conditions

| Parameter | Symbol | Condition | Min. | Typ. | Max. | Unit |
|---|--------------|----------------|------|------|------|------|
| Operating case temperature range | T_{case} | | 0 | | +70 | °C |
| Relative humidity range | RH | Non condensing | 5 | | 85 | % |
| Operating wavelength range | λ | | 1520 | | 1580 | nm |
| Substrate bias voltage | V_{sub} | | 8 | 10 | 15 | V |
| Child MZM Quadrature Control Bias Voltage 1&2 | V_{QCC1-2} | | -7 | | 7 | V |
| Parent MZM Quadrature Control Bias Voltage | V_{QCP} | | -7 | | 7 | V |
| Max optical input power (CW) | P_{opt} | | | | 20 | dBm |
| Max RF input power | P_{in} | | | | 21 | dBm |

Optical and Electrical Specifications

| Parameter | Symbol | Condition | Min. | Typ. | Max. | Unit |
|--------------------------------|--------------|-----------------------|------|------|------|------|
| Optical insertion loss | IL | Room temperature | | 7 | 8.5 | dB |
| Half wave drive voltage | V_{π} | to 20 Gbit/s | | 3.0 | 3.2 | V |
| Electrical to optical response | E/O S_{21} | S_{21} , 3 dB point | 18 | 20 | | GHz |
| Extinction ratio | ER | Low frequency | 18 | 20 | | dB |

Typical Performance and Mechanical Dimensions

